

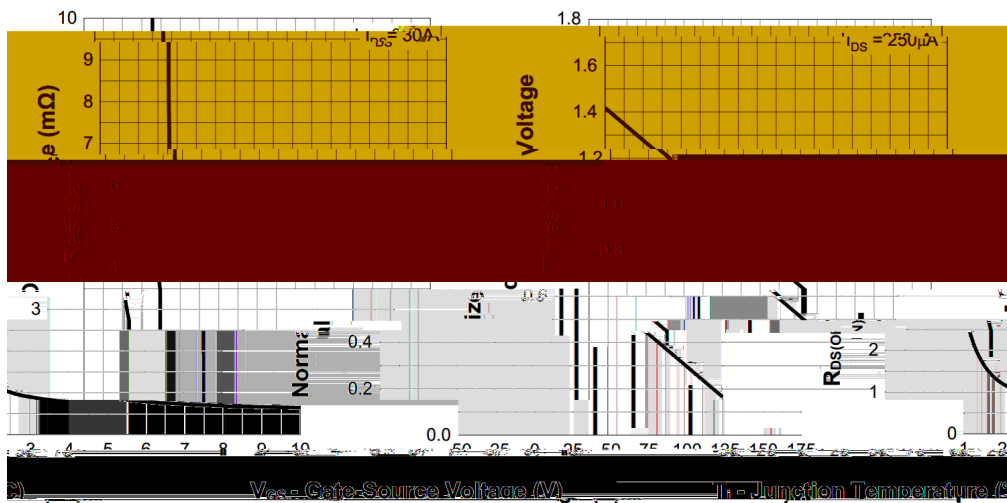
Parameter	Symbol	Rating	Unit
Drain-Source Voltage	V_{DS}	60	V
Drain Current	$I_D(T_C=25^\circ\text{C})$	300	A
	$I_D(T_C=100^\circ\text{C})$	300	A
Pulsed Drain Current	I_{DM}	1200	A
Gate-Source Voltage	V_{GS}	± 20	V
Single Pulsed Avalanche Energy $L=1.0\text{mH}$	E_{AS}	1000	mJ
Continuous-Source Current	I_S	300	A
Total Power Dissipation	$P_D(T_C=25^\circ\text{C})$	375	W
Junction and Storage Temperature Range	T_J, T_{STG}	-55 to 175	$^\circ\text{C}$
Thermal Resistance-Junction to Ambient	$R_{\theta JA}$	60	/W
Thermal Resistance-Junction to Case	$R_{\theta JC}$	0.4	

Notes:

- ① Surface Mounted on 1 in² pad area, $t \leq 10$ sec
- ② Pulse width $\leq 300 \mu\text{s}$, duty cycle $\leq 2\%$
- ③ Limited by bonding wire

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Drain-Source Breakdown Voltage	BV_{DSS}	$V_{GS}=0V$ $I_D=250\mu A$	60			V
Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS}=48V$ $V_{GS}=0V$			1	μA
Gate-Body Leakage Current Forward	I_{GSS}	$V_{GS}=\pm 20V$ $V_{DS}=0V$			± 100	nA
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}$ $I_D=250\mu A$	1		2.5	V
Static Drain-Source On-Resistance	$R_{DS(on)}$	$V_{GS}=10V$ $I_D=30A$		0.67	0.75	m Ω
	$R_{DS(on)}$	$V_{GS}=4.5V$ $I_D=20A$		1.10	1.25	m Ω
Drain-Source Diode Forward Voltage	V_{SD}	$V_{GS}=0V$ $I_S=30A$			1.3	V
Reverse Recovery Time	t_{rr}	$I_{DS} = 30 A, V_{GS} = 0 V$ $dI_{SD}/dt = 100 A/\mu s$		85		nS
Reverse Recovery Charge	Q_{rr}			120		nC
Input Capacitance	C_{iss}	$V_{DS}=30V$ $V_{GS}=0V$ $f=1.0\text{MHz}$		7204		pF
Output Capacitance	C_{oss}			2154		
Reverse Transfer Capacitance	C_{rss}			249		

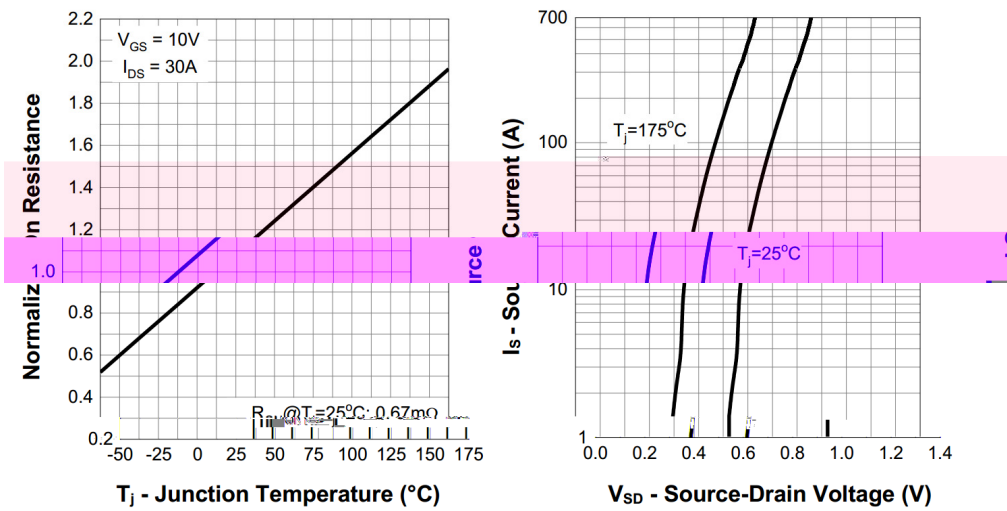
Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Total Gate Charge	Q_g	$V_{GS}=10V,$ $V_{DS}=30V,$ $I_D=30A$		155		nC



Old Voltage

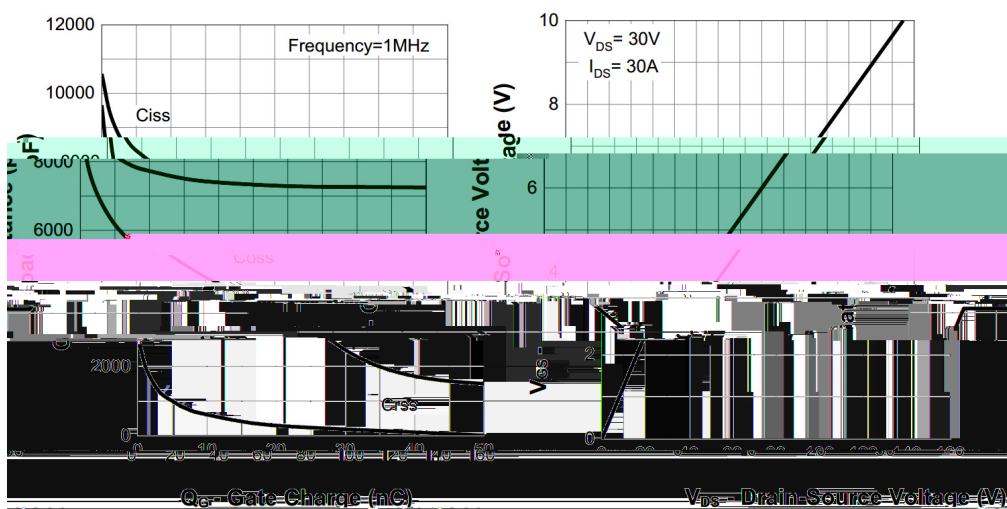
7. Transfer Characteristics

8. Normalized Threshold



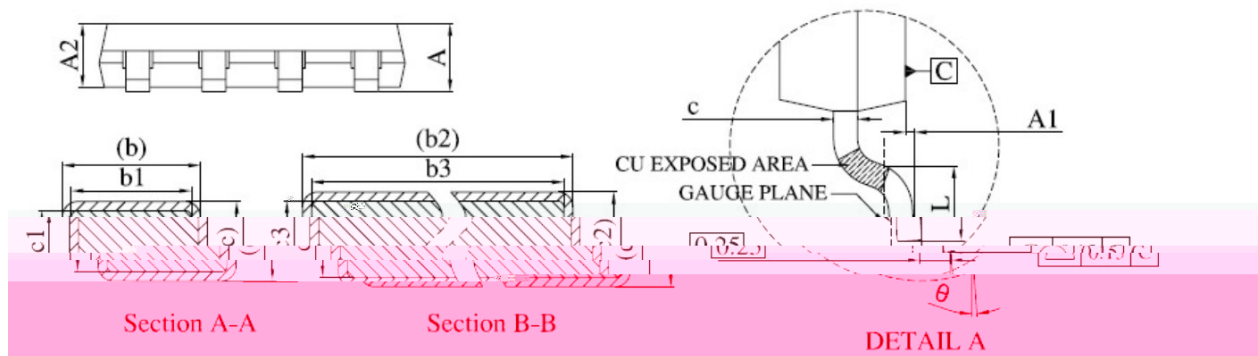
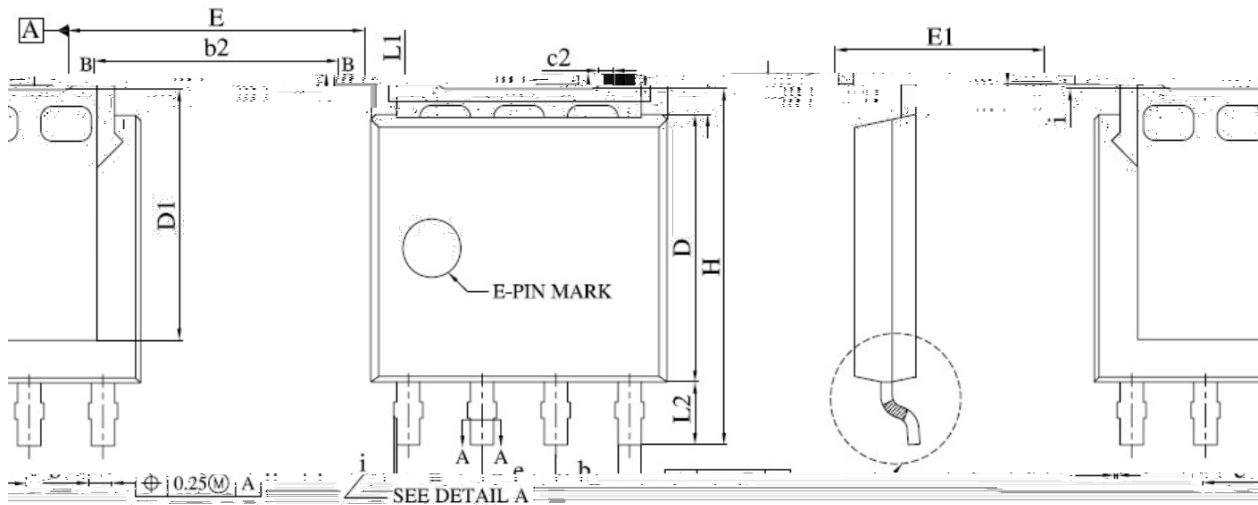
9. Normalized On Resistance

10. Diode Forward Current



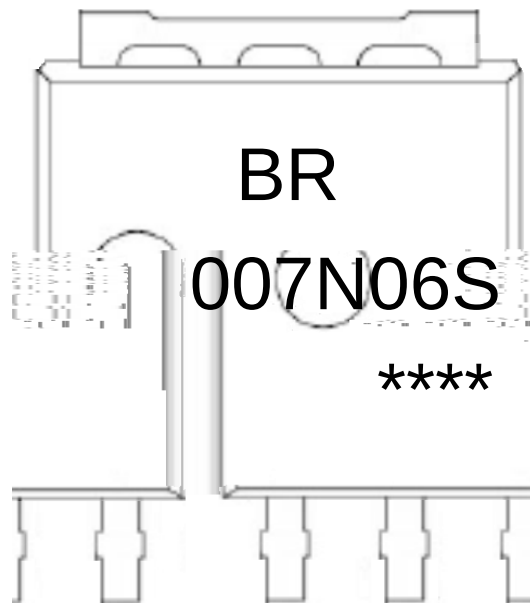
12. Gate Charge

11. Capacitance



Symbol	Dimensions In Millimeters	
	MIN.	MAX.
A	1.00	1.30
A1	0.00	0.15
A2	0.98	1.12
b	0.35	0.50
b1	0.32	0.46
b2	4.02	4.41
b3	4.00	4.37
c	0.19	0.25
c1	0.17	0.23
c2	0.24	0.30
c3	0.22	0.28
D	4.45	4.70
D1	-	4.45

Symbol	Dimensions In Millimeters	
	MIN.	MAX.
E	4.95	5.30
E1	3.50	3.70
e	1.27 BSC.	
H	5.95	6.00
i	-	0.10
L	0.40	0.85
L1	0.27	0.57
L2	0.80	1.30
θ	0°	8°



BR

007N06S

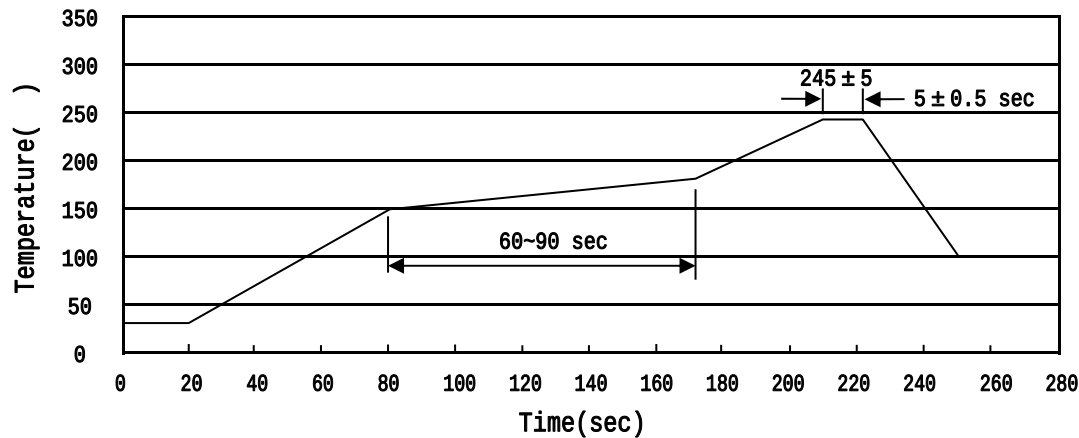
Note

BR: Company Code

007N06S: Product Type Code

****: Lot No. Code, code change with Lot No.

Temperature Profile for IR Reflow Soldering(Pb-Free)



Note:

- | | | | | | |
|---|-------|-----|----|-----------|---|
| 1 | 150 | 180 | 60 | 90sec; | 1.Preheating:150~180 , Time:60~90sec. |
| 2 | 245±5 | | | 5±0.5sec; | 2.Peak Temp.:245±5 , Duration:5±0.5sec. |
| 3 | | 2 | 10 | /sec. | 3. Cooling Speed: 2~10 /sec. |

260±5 10±1 sec. Temp.:260±5℃ Time:10±1 sec

/ REEL

Package Type	Units					Dimension (unit mm ³)		
	/	/	/	/	/			
LFPAK5×6	3,000	2	6,000	5	30,000	13"×12	356×335×50	385×285×358

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